

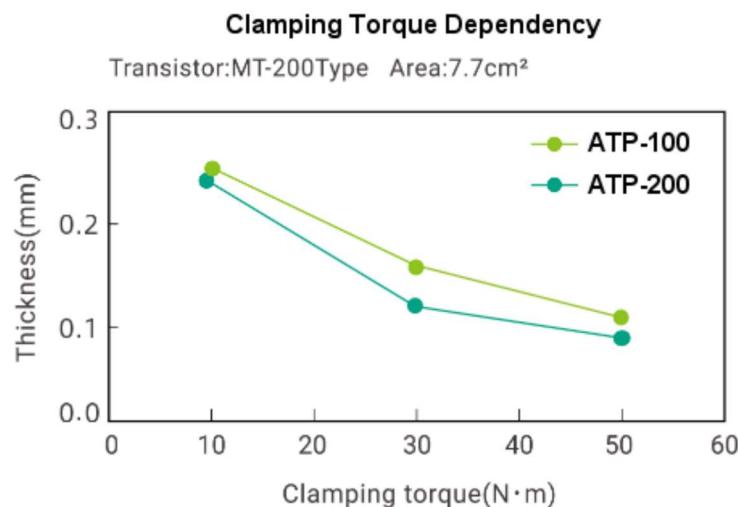
## THERMAL PASTE

series: ATP



	<ul style="list-style-type: none"> <li>• Eliminates air gaps between heat source and heat sink.</li> <li>• High thermal conductivity of up to 6.5w/mk.</li> <li>• Molecular structure prevents leakage and vaporization.</li> <li>• Long term reliability.</li> <li>• Good electrical insulation.</li> <li>• Low rebound reduces load on electronic components.</li> <li>• Compresses easily, absorbing dimensional tolerances.</li> <li>• Typical applications include PCBs in automotive navigation systems, CIDs and ECUs, tablet devices, digital cameras, digital signage and manufacturing equipment.</li> </ul>
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Properties	ATP-100	ATP-200	
Thermal Conductivity (W/m-k) – Our tests Hot wire method	6.5 2.0	4.8 1.6	
Hardness (Cone Penetration (1/10mm), not mixed)	51	55	
Appearance	Gray	Gray	
Specific Gravity	2.8	2.6	
Volume Resistivity ( $\Omega \cdot \text{cm}$ )	5.9x10	7.2x10	
Dielectric Breakdown Strength (kV/mm)	5.0	5.6	
Dielectric Constant <50Hz> <1KHz> <1MHz>	8.9 7.8 7.0	7.6 6.7 6.6	
Dielectric Dissipation Factor <50Hz> <1KHz> <1MHz>	0.234 0.061 0.015	0.017 0.007 0.005	
Thermal Resistance ( $^{\circ}\text{C}/\text{W}$ ) Transistor: MT-200 Heat Input: 20V	Thickness (mm) 0.10 0.15 0.20 0.30	- 0.13 0.15 0.18 0.13 0.17 0.22	
Low Molecular Weight Siloxane Level D4-10 (ppm)	Solvent Extraction Method Head Space Method	Less than 700 Less than 1	Less than 900 Less than 3
Temperature Range ( $^{\circ}\text{C}$ )		-40 ~ 200 -40 ~ 200	



#### Thermal Resistance

Thickness (mm)	0.10	0.15	0.20	0.30
ATP-100	-	0.13	0.15	0.18
ATP-200	0.13	-	0.17	0.22

Transistor: MT-200 Type

Heat input: 20V  
(°C)